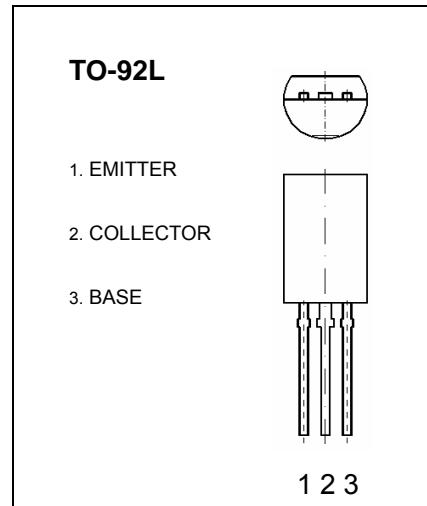


**2SA1013** TRANSISTOR (PNP)**FEATURE**

- **High voltage:**  $V_{CEO}=-160V$
- **Large continuous collector current capability**
- **Complementary to 2SC2383**

**MAXIMUM RATINGS ( $T_A=25^\circ C$  unless otherwise noted)**

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	-160	V
$V_{CEO}$	Collector-Emitter Voltage	-160	V
$V_{EBO}$	Emitter-Base Voltage	-6	V
$I_c$	Collector Current -Continuous	-1	A
$P_c$	Collector Power Dissipation	0.9	W
$T_j$	Junction Temperature	150	$^\circ C$
$T_{stg}$	Storage Temperature	-55 to +150	$^\circ C$

**ELECTRICAL CHARACTERISTICS ( $T_{amb}=25^\circ C$  unless otherwise specified)**

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-100\mu A, I_E=0$	-160		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=-1mA, I_B=0$	-160		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-10\mu A, I_C=0$	-6		V
Collector cut-off current	$I_{CBO}$	$V_{CB}=-150 V, I_E=0$		-1	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=-6V, I_C=0$		-1	$\mu A$
DC current gain	$h_{FE}$	$V_{CE}=-5 V, I_C=-200mA$	60	320	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=-500mA, I_B=-50mA$		-1.5	V
Base-emitter voltage	$V_{BE}$	$I_C=-5 mA, V_{CE}=-5V$		-0.75	V
Transition frequency	$f_T$	$V_{CE}=-5 V, I_C=-200mA$	15		MHz
Collector Output capacitance	$C_{ob}$	$V_{CB}=-10V, I_E=0, f=1MHz$		35	pF

**CLASSIFICATION OF  $h_{FE}$** 

Rank	R	O	Y
Range	60-120	100-200	160-320